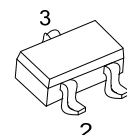


**BAS70xW****DIODE****SCHOTTKY BARRIER
DIODES****■ DESCRIPTION**

Planar Schottky barrier diodes encapsulated in the SOT-323 small plastic SMD package. Single diode and dual diodes with different pin configuration are available.

■ FEATURES

- * Low Turn-on voltage
- * Fast switching
- * Ultra-small surface mount package
- * Also available in lead free version



SOT-323

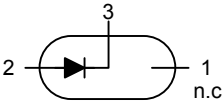
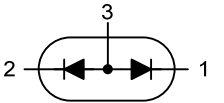
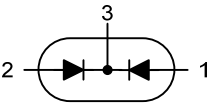
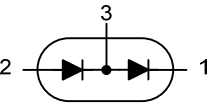
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
BAS70WL-AL3-R	BAS70WG-AL3-R	SOT-323	x	A	K	Tape Reel
BAS70AWL-AL3-R	BAS70AWG-AL3-R	SOT-323	K1	K2	A2A1	Tape Reel
BAS70CWL-AL3-R	BAS70CWG-AL3-R	SOT-323	A1	A2	K2K1	Tape Reel
BAS70SWL-AL3-R	BAS70SWG-AL3-R	SOT-323	K1	A2	K2A1	Tape Reel

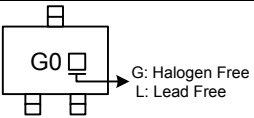
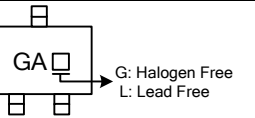
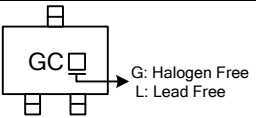
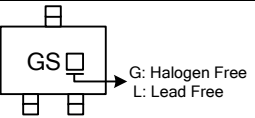
Note: Pin Assignment: A: Anode K: Cathode x: NC

BAS70xWL-AE3-R (1) Packing Type (2) Package Type (3) Lead Free (4) Pin Assignment	(1) R: Tape Reel (2) AL3: SOT-323 (3) L: Lead Free, G: Halogen Free (4) x: refer to Pin Assignment
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DIODE CONFIGURATION AND SYMBOL

BAS70W	BAS70AW	BAS70CW	BAS70SW
			

MARKING

BAS70W	BAS70AW	BAS70CW	BAS70SW
			

■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNITS
DC Voltage	V_R	70	V
Forward Continuous Current	I_F	70	mA
Power Dissipation	P_D	150	mW
Junction Temperature	T_J	-55 ~ +150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55 ~ +150	$^{\circ}\text{C}$

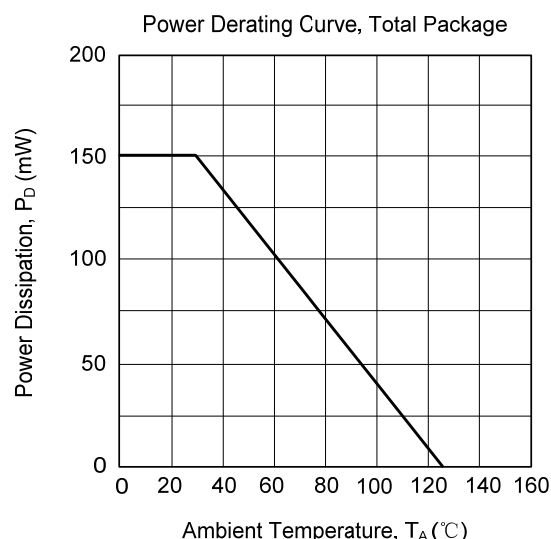
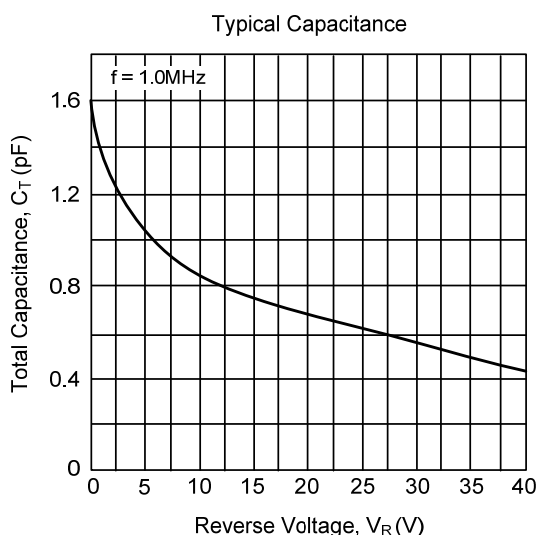
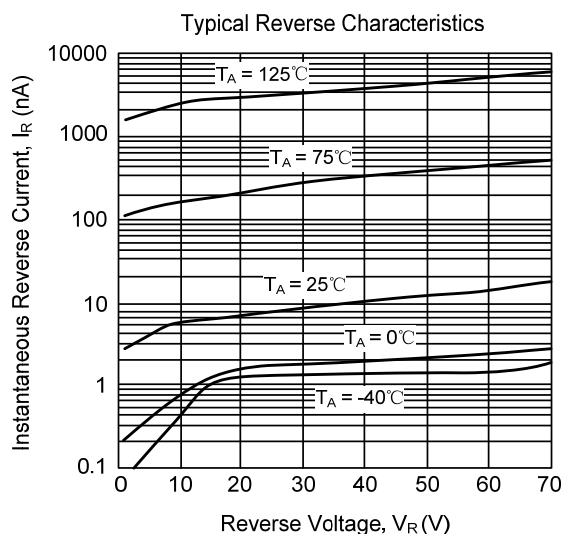
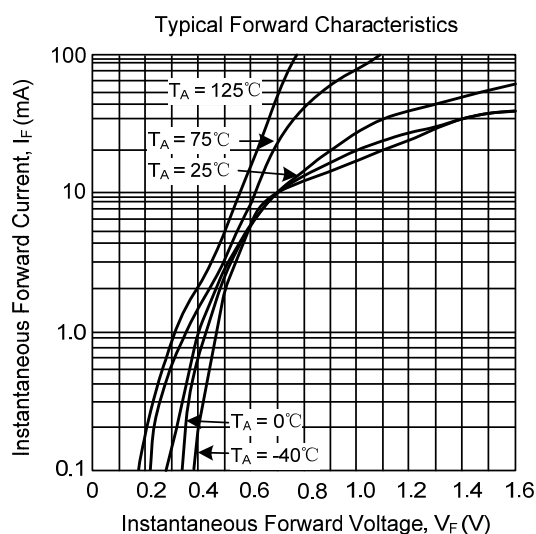
Note Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage	BV_R	$I_R=10\mu\text{A}$	70			V
Reverse Voltage Leakage Current	I_R	$V_R=50\text{V}$			200	nA
Forward Voltage	V_F	$I_F=1\text{mA}$			410	mV
		$I_F=15\text{mA}$			1000	mV
Diode Capacitance	C_D	$V_R=0\text{V}$, $f=1\text{MHz}$			2	pF
Reverse Recovery Time	t_{RR}	$I_F=I_R=10\text{mA}$, $I_{RR}=0.1 \times I_R$, $R_L=100\Omega$			5	nS

■ TYPICAL CHARACTERISTICS



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